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2.5V / 3.3V 1:5 Dual Differential ECL/PECL/HSTL Clock Driver

Description

The MC100LVEP210 is a low skew 1–to–5 dual differential driver, designed with clock distribution in mind. The ECL/PECL input signals can be either differential or single–ended if the V_{BB} output is used. The signal is fanned out to 5 identical differential outputs. HSTL inputs can be used when the EP210 is operating in PECL mode.

The LVEP210 specifically guarantees low output-to-output skew. Optimal design, layout, and processing minimize skew within a device and from device to device.

To ensure the tight skew specification is realized, both sides of the differential output need to be terminated identically into 50 Ω even if only one output is being used. If an output pair is unused, both outputs may be left open (unterminated) without affecting skew.

The MC100LVEP210, as with most other ECL devices, can be operated from a positive V_{CC} supply in PECL mode. This allows the LVEP210 to be used for high performance clock distribution in +3.3 V or +2.5 V systems. Single–ended CLK input operation is limited to a V_{CC} \geq 3.0 V in PECL mode, or V_{EE} \leq -3.0 V in ECL mode.

Designers can take advantage of the LVEP210's performance to distribute low skew clocks across the backplane or the board. In a PECL environment, series or Thevenin line terminations are typically used as they require no additional power supplies. For more information on using PECL, designers should refer to Application Note AN1406/D.

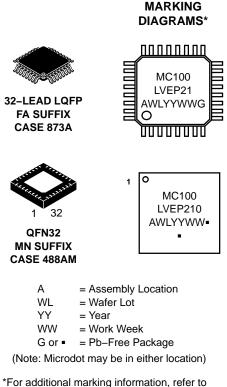
Features

- 85 ps Typical Device-to-Device Skew
- 20 ps Typical Output-to-Output Skew
- V_{BB} Output
- Jitter Less than 1 ps RMS
- 350 ps Typical Propagation Delay
- Maximum Frequency > 3 GHz Typical
- The 100 Series Contains Temperature Compensation
- PECL and HSTL Mode Operating Range: $V_{CC} = 2.375$ V to 3.8 V with $V_{EE} = 0$ V
- NECL Mode Operating Range: $V_{CC} = 0 V$ with $V_{EE} = -2.375 V$ to -3.8 V
- Open Input Default State
- LVDS Input Compatible
- Fully Compatible with MC100EP210
- These are Pb–Free Devices



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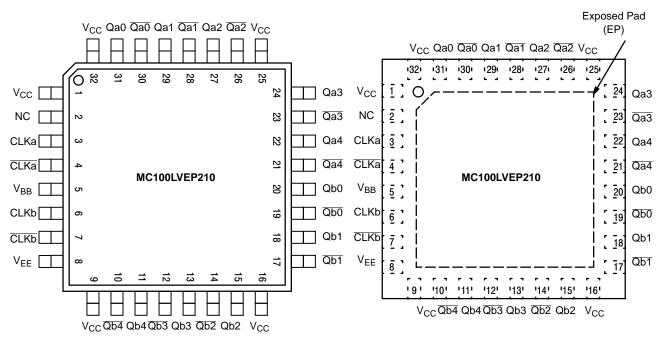
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For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.



Warning: All V_{CC} and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

Figure 1. 32-Lead QFN Pinout (Top View)

Figure 2. LQFP-32 Pinout (Top View)

Table 1. PIN DESCRIPTION

PIN	FUNCTION
CLKn*, CLKn**	ECL/PECL/HSTL CLK Inputs
Qn0:4, Qn0:4	ECL/PECL Outputs
V _{BB}	Reference Voltage Output
V _{CC}	Positive Supply
V _{EE}	Negative Supply
EP	The exposed pad (EP) on the QFN–32 package bottom is thermally connected to the die for improved heat transfer out of the package. THe exposed pad must be attached to a heat–sinking conduit. The pad is electrically connected to V_{EE} .

* Pins will default LOW when left open.

** Pins will default to $V_{CC}/2$ when left open.

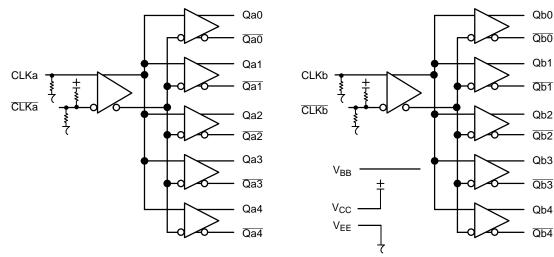


Figure 3. Logic Diagram

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Table 2. ATTRIBUTES

Characterist	Value			
Internal Input Pulldown Resistor	75 kΩ			
Internal Input Pull-up Resistor	37.5	5 kΩ		
ESD Protection	> 1(⊧kV 00 V ⊧kV		
Moisture Sensitivity (Note 1)		Pb Pkg	Pb-Free Pkg	
	LQFP-32 QFN-32	Level 2 N/A	Level 2 Level 1	
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in		
Transistor Count	461 Devices			
Meets or exceeds JEDEC Spec EIA				

1. For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		6	V
V_{EE}	NECL Mode Power Supply	$V_{CC} = 0 V$		-6	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$V_I \leq V_{CC} \\ V_I \geq V_{EE}$	6 6	V V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
I _{BB}	V _{BB} Sink/Source			± 0.5	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	LQFP-32 LQFP-32	80 55	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	LQFP-32	12 to 17	°C/W
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	QFN-32 QFN-32	31 27	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	2S2P	QFN-32	12	°C/W
T _{sol}	Wave Solder Pb Pb-Free	<2 to 3 sec @ 248°C <2 to 3 sec @ 260°C		265 265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

		−40°C		25°C							
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	55	70	90	55	70	90	55	70	90	mA
V _{OH}	Output HIGH Voltage (Note 3)	1355	1480	1605	1355	1480	1605	1355	1480	1605	mV
V _{OL}	Output LOW Voltage (Note 3)	505	680	900	505	680	900	505	680	900	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 4)	1.2		2.5	1.2		2.5	1.2		2.5	V
V _{IL}	Input LOW Voltage (Single-Ended)	505		900	505		900	505		900	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150			μΑ

Table 4. PECL DC CHARACTERISTICS V_{CC} = 2.5 V; V_{FF} = 0 V (Note 2)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

2. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary + 0.125 V to -1.3 V.

3. All loading with 50 Ω to V_{EE}. 4. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

		−40°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	55	70	90	55	70	90	55	70	90	mA
V _{OH}	Output HIGH Voltage (Note 6)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
V _{OL}	Output LOW Voltage (Note 6)	1305	1480	1700	1305	1480	1700	1305	1480	1700	mV
VIH	Input HIGH Voltage (Single–Ended)			2420	2135		2420	2135		2420	mV
V _{IL}	Input LOW Voltage (Single-Ended)			1700	1305		1700	1305		1700	mV
V _{BB}	Output Reference Voltage (Note 7)	1775	1875	1975	1775	1875	1975	1775	1875	1975	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 8)			3.3	1.2		3.3	1.2		3.3	V
I _{IH}	Input HIGH Current			150			150			150	μA
IL	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

5. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary + 0.925 V to -0.5 V.

6. All loading with 50 Ω to V_{CC} – 2.0 V.

7. Single-ended input operation is limited $V_{CC} \ge 3.0$ V in PECL mode. 8. V_{IHCMR} min varies 1:1 with V_{EE} , V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

		-40°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	55	70	90	55	70	90	55	70	90	mA
V _{OH}	Output HIGH Voltage (Note 10)	-1145	-1020	-895	-1145	-1020	-895	-1145	-1020	-895	mV
V _{OL}	Output LOW Voltage (Note 10)	-1995	-1820	-1600	-1995	-1820	-1600	-1995	-1820	-1600	mV
V _{IH}	Input HIGH Voltage (Single–Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V _{IL}	Input LOW Voltage (Single-Ended)	-1995		-1600	-1995		-1600	-1995		-1600	mV
V_{BB}	Output Reference Voltage (Note 11)	-1525	-1425	-1325	-1525	-1425	-1325	-1525	-1425	-1325	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 12)	V _{EE}	+ 1.2	0.0	V _{EE} ·	+ 1.2	0.0	V _{EE} -	+ 1.2	0.0	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current CLK CLK	0.5 -150			0.5 -150			0.5 -150		150	μΑ

Table 6. NECL DC CHARACTERISTICS $V_{CC} = 0 V$, $V_{EE} = -2.375 V$ to -3.8 V (Note 9)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

9. Input and output parameters vary 1:1 with V_{CC}.

10. All loading with 50 Ω to V_{CC} – 2.0 V. 11. Single–ended input operation is limited V_{EE} \leq –3.0V in NECL mode.

12. VIHCMR min varies 1:1 with VEE, VIHCMR max varies 1:1 with VCC. The VIHCMR range is referenced to the most positive side of the differential input signal.

Table 7. HSTL DC CHARACTERISTICS $V_{CC} = 2.375$ to 3.8 V, $V_{EE} = 0$ V

		−40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
VIH	Input HIGH Voltage	1200			1200			1200			mV
VIL	Input LOW Voltage			400			400			400	mV
V _{CM}	Input Crossover Voltage	680		900	680		900	680		900	mV
I _{CC}	Power Supply Current (Outputs Open)	55	70	90	55	70	90	55	70	90	mA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

			–40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{maxPECL} / HSTL	Maximum Frequency (Figure 4)		3			3			3		GHz
t _{PLH} /t _{PHL}	Propagation Delay @ 2.5 V Propagation Delay @ 3.3 V	220 220	300 300	380 380	270 270	350 350	430 430	300 330	400 410	500 490	ps
t _{skew}	Within–Device Skew (Note 14) Device–to–Device Skew (Note 15)		20 85	25 160		20 85	25 160		20 85	35 160	ps
^t JITTER	CLOCK Random Jitter (RMS) @ ≤ 0.5 GHz @ ≤ 1.0 GHz @ ≤ 1.5 GHz @ ≤ 2.0 GHz @ ≤ 2.5 GHz @ ≤ 3.0 GHz		0.184 0.190 0.178 0.196 0.239 0.336	0.3 0.3 0.3 0.3 0.4 0.5		0.207 0.200 0.197 0.233 0.301 0.422	0.3 0.3 0.3 0.4 0.4 0.5		0.271 0.252 0.259 0.308 0.399 0.572	0.4 0.4 0.5 0.5 0.9	ps
V _{PP}	Minimum Input Swing	150	800	1200	150	800	1200	150	800	1200	mV
t _r /t _f	Output Rise/Fall Time (20%-80%)	100	170	250	120	190	270	150	280	350	ps

Table 8. AC CHARACTERISTICS $V_{CC} = 0 V$; V	$V_{EE} = -2.375$ to -3.8 V or V ₀	_{CC} = 2.375 to 3.8 V; V _{EE} = 0 V (Note 13)
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NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

13. Measured with 750 mV source, 50% duty cycle clock source. All loading with 50 Ω to V_{CC} – 2.0 V.

14. Skew is measured between outputs under identical transitions of similar paths through a device.

15. Device-to-Device skew for identical transitions at identical V_{CC} levels.

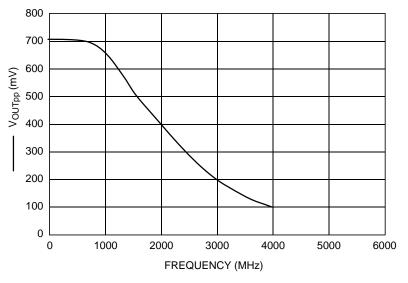


Figure 4. F_{max} Typical

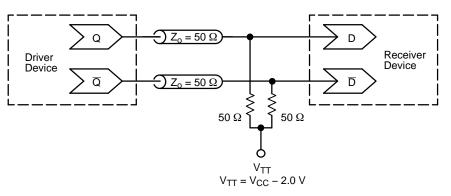


Figure 5. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

ORDERING INFORMATION

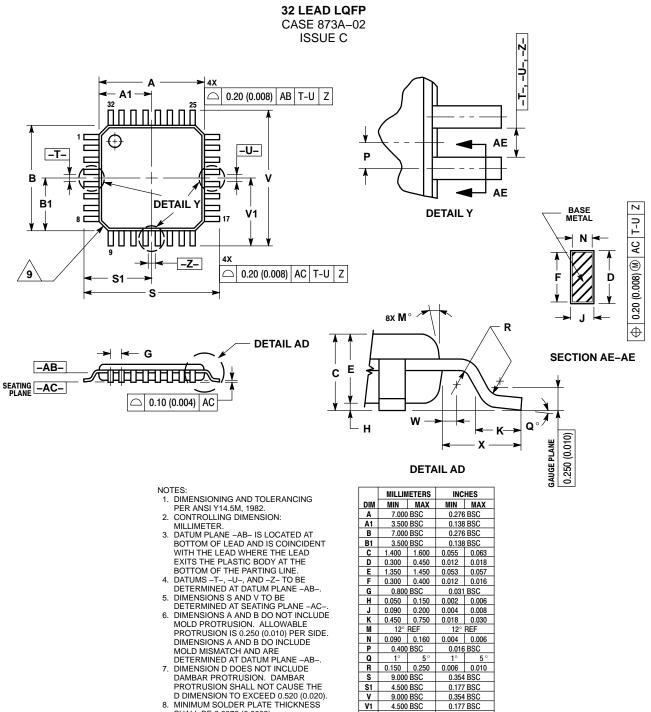
Device	Package	Shipping [†]
MC100LVEP210FAG	LQFP (Pb–Free)	250 Units / Tray
MC100LVEP210FARG	LQFP (Pb-Free)	2000 / Tape & Reel
MC100LVEP210MNG	QFN32 (Pb–Free)	74 Units / Rail
MC100LVEP210MNR2G	QFN32 (Pb-Free)	1000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Resource Reference of Application Notes

AN1405/D	_	ECL Clock Distribution Techniques
AN1406/D	_	Designing with PECL (ECL at +5.0 V)
AN1503/D	_	ECLinPS [™] I/O SPiCE Modeling Kit
AN1504/D	_	Metastability and the ECLinPS Family
AN1568/D	-	Interfacing Between LVDS and ECL
AN1672/D	_	The ECL Translator Guide
AND8001/D	-	Odd Number Counters Design
AND8002/D	-	Marking and Date Codes
AND8020/D	-	Termination of ECL Logic Devices
AND8066/D	-	Interfacing with ECLinPS
AND8090/D	_	AC Characteristics of ECL Devices

PACKAGE DIMENSIONS



- SHALL BE 0.0076 (0.0003). EXACT SHAPE OF EACH CORNER MAY
- 9. VARY FROM DEPICTION.

WX

0.200 REF

1.000 REF

0.008 REF

0.039 REF